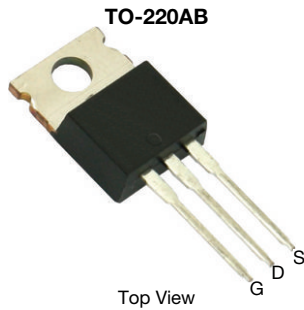


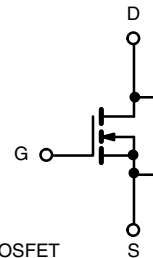
Automotive N-Channel 200 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE


PRODUCT SUMMARY	
V _{DS} (V)	200
R _{DS(on)} (Ω) at V _{GS} = 10 V	0.0153
I _D (A)	78.5
Configuration	Single
Package	TO-220

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	200	V
Gate-source voltage		V _{GS}	± 20	
Continuous drain current	T _C = 25 °C	I _D	78.5	A
	T _C = 125 °C		45	
Continuous source current (diode conduction) ^a		I _S	120	
Pulsed drain current ^b		I _{DM}	170	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	64	
Single pulse avalanche energy		E _{AS}	205	mJ
Maximum power dissipation ^b	T _C = 25 °C	P _D	250	W
	T _C = 125 °C		83	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W
Junction-to-case (drain)		R _{thJC}	0.6	

Notes

- Package limited.
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR4 material).



SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	200	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	2.5	3.0	3.5	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 200 V	-	-	1	μA
		V _{GS} = 0 V, V _{DS} = 200 V, T _J = 125 °C	-	-	50	
		V _{GS} = 0 V, V _{DS} = 200 V, T _J = 175 °C	-	-	600	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V, V _{DS} ≥ 5 V	40	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 20 A	-	0.0127	0.0153	Ω
		V _{GS} = 10 V, I _D = 20 A, T _J = 125 °C	-	-	0.0310	
		V _{GS} = 10 V, I _D = 20 A, T _J = 175 °C	-	-	0.0404	
Forward transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 20 A	-	54	-	S
Dynamic ^b						
Input capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz	-	3200	4200	pF
Output capacitance	C _{oss}		-	1300	1750	
Reverse transfer capacitance	C _{rss}		-	80	110	
Total gate charge ^c	Q _g	V _{GS} = 10 V, V _{DS} = 100 V, I _D = 9 A	-	55	85	nC
Gate-source charge ^c	Q _{gs}		-	14	-	
Gate-drain charge ^c	Q _{gd}		-	16.5	-	
Gate Resistance	R _g	f = 1 MHz	1.40	2.92	4.40	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = 100 V, R _L = 11.1 Ω I _D ≅ 9 A, V _{GEN} = 10 V, R _g = 1 Ω	-	17	30	ns
Rise time ^c	t _r		-	8	15	
Turn-off delay time ^c	t _{d(off)}		-	39	60	
Fall time ^c	t _f		-	16	30	
Source-Drain Diode Ratings and Characteristics ^b						
Pulsed current ^a	I _{SM}		-	-	170	A
Forward voltage	V _{SD}	I _F = 20 A, V _{GS} = 0 V	-	0.82	1.5	V
Body diode reverse recovery time	t _{rr}	I _F = 10 A, di/dt = 100 A/μs	-	129	260	ns
Body diode reverse recovery charge	Q _{rr}		-	685	1400	nC
Reverse recovery fall time	t _a		-	106	-	ns
Reverse recovery rise time	t _b		-	26	-	
Body diode peak reverse recovery current	I _{RM(REC)}		-	-	-11	-

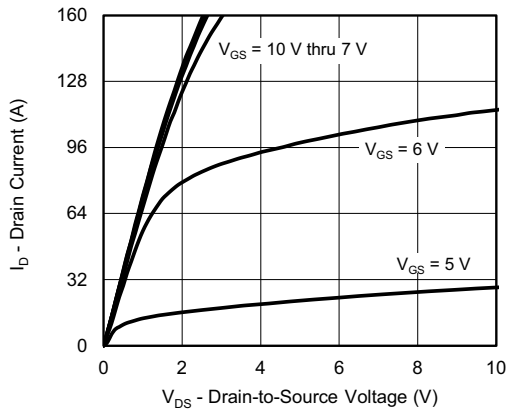
Notes

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

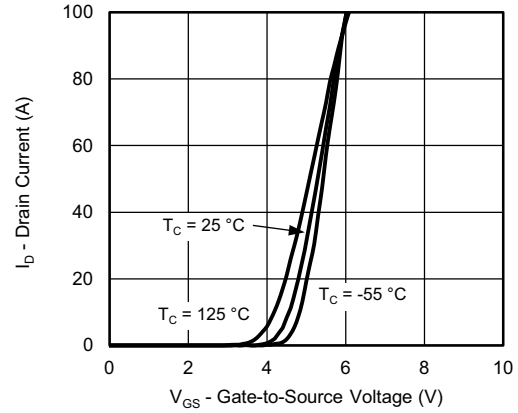
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



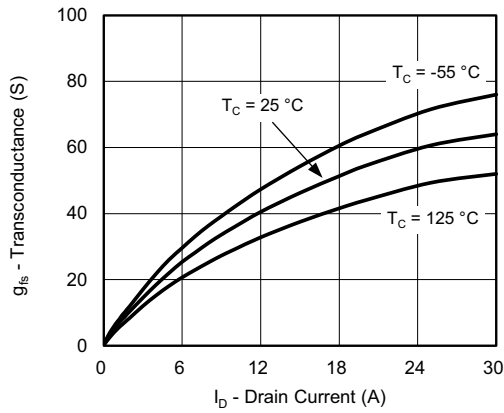
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



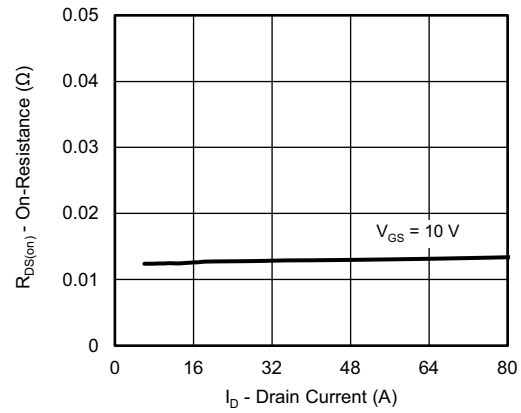
Output Characteristics



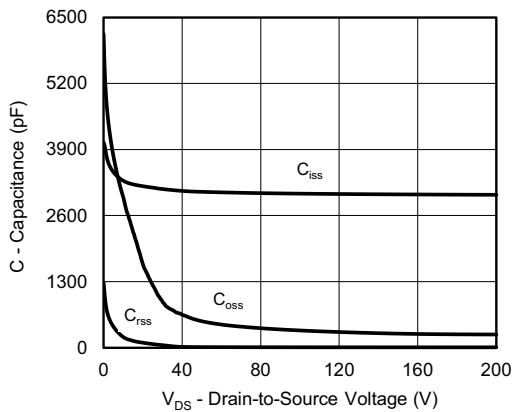
Transfer Characteristics



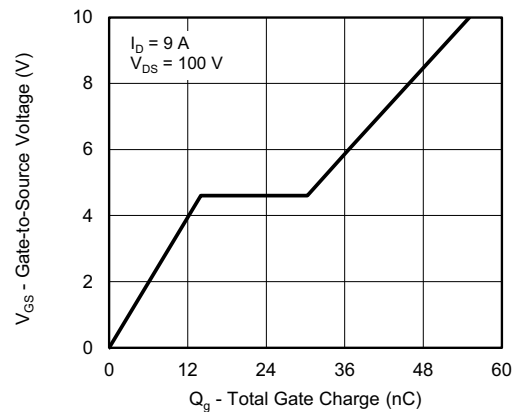
Transconductance



On-Resistance vs. Drain Current



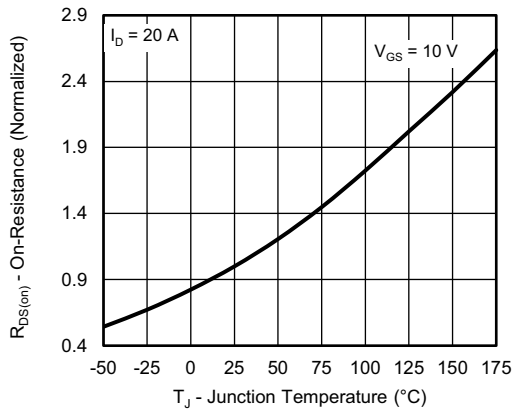
Capacitance



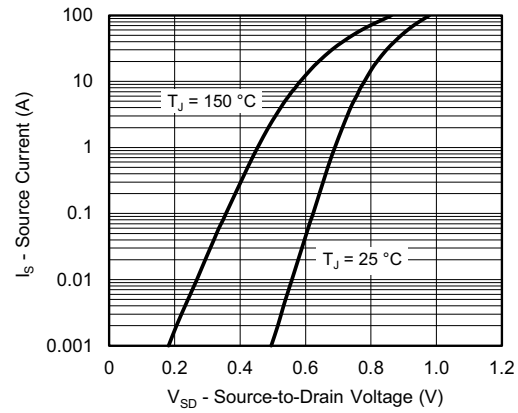
Gate Charge



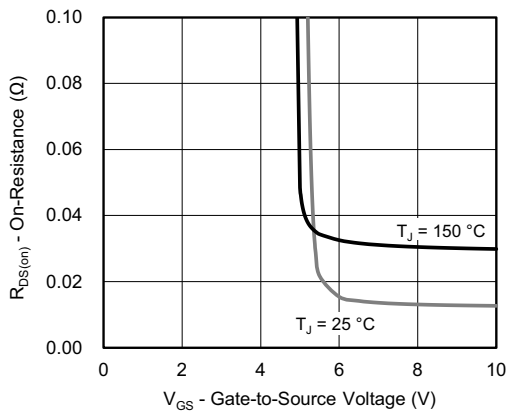
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



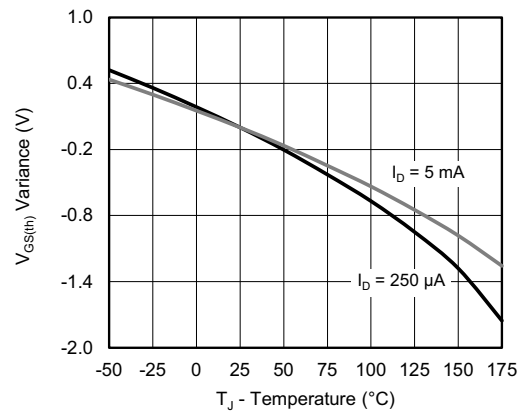
On-Resistance vs. Junction Temperature



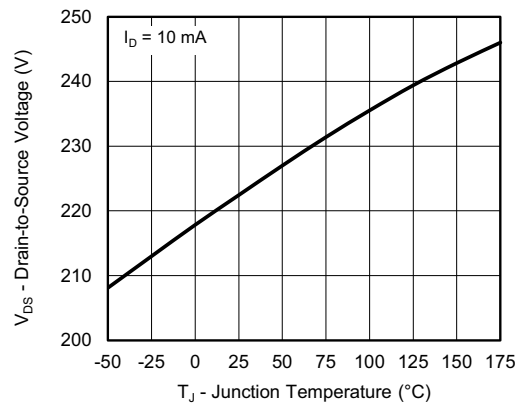
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



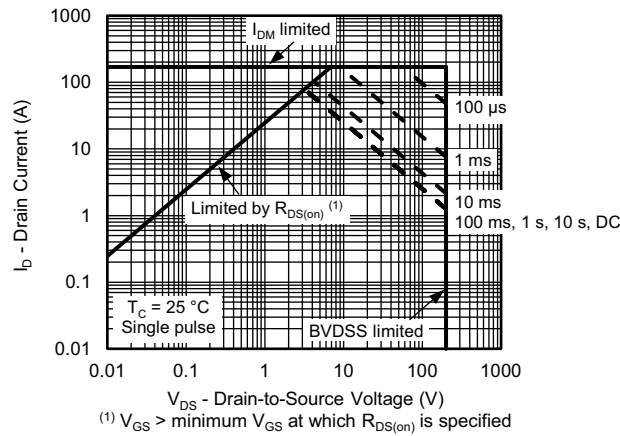
Threshold Voltage



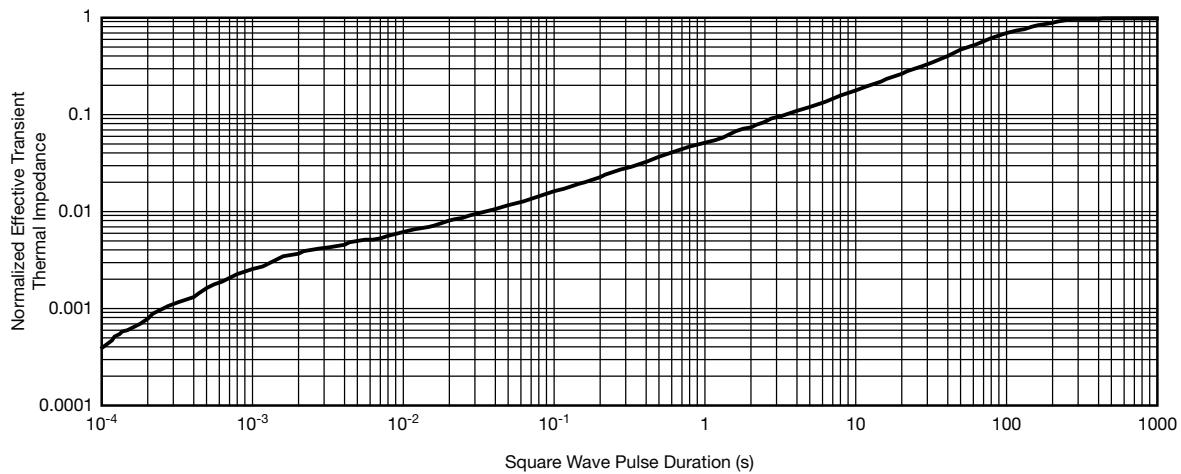
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



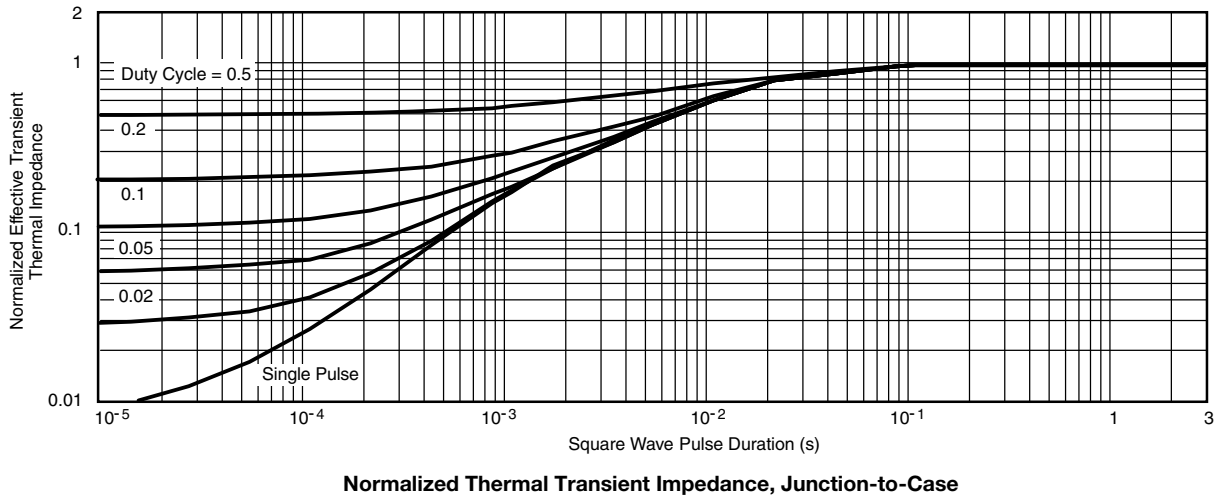
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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